

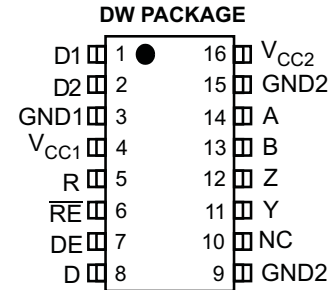


Isolated 3.3V RS-485 Transceiver With Integrated Transformer Driver

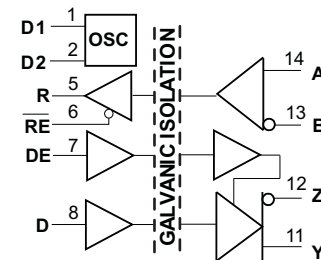
Check for Samples: [ISO35T](#)

FEATURES

- **3000V_{RMS} / 4242V_{PK} Isolation**
- **Bus-Pin ESD Protection**
 - 16 kV HBM Between Bus-Pins and GND2
 - 6 kV HBM Between Bus-Pins and GND1
- **1/8 Unit Load – Up to 256 Nodes on a Bus**
- **Designed for RS-485 and RS-422 Applications**
- **Signaling Rates up to 1 Mbps**
- **Thermal Shutdown Protection**
- **Typical Efficiency > 60% (I_{LOAD} = 100 mA)**
- see [SLUU470](#)
- **Low Driver Bus Capacitance 16 pF (Typ)**
- **50 kV/μs Typical Transient Immunity**
- **UL 1577, IEC 60747-5-2 (VDE 0884, Rev. 2) Approvals Pending**
- **Fail-safe Receiver for Bus Open, Short, Idle**
- **Logic Inputs are 5-V Tolerant**



FUNCTION DIAGRAM



APPLICATIONS

- **Isolated RS-485/RS-422 Interfaces**
- **Factory Automation**
- **Motor/Motion Control**
- **HVAC and Building Automation Networks**
- **Networked Security Stations**

DESCRIPTION

The ISO35T is an isolated differential line transceiver with integrated oscillator outputs that provide the primary voltage for an isolation transformer. The device is a full-duplex differential line transceiver for RS-485 and RS-422 applications that can easily be configured for half-duplex operation by connecting pin 11 to pin 14, and pin 12 to pin 13.

These devices are ideal for long transmission lines since the ground loop is broken to allow for a much larger common-mode voltage range. The symmetrical isolation barrier of the device is tested to provide 4242V_{PK} of isolation per VDE for 60s between the bus-line transceiver and the logic-level interface.

Any cabled I/O can be subjected to electrical noise transients from various sources. These noise transients can cause damage to the transceiver and/or near-by sensitive circuitry if they are of sufficient magnitude and duration. The ISO35T can significantly reduce the risk of data corruption and damage to expensive control circuits.

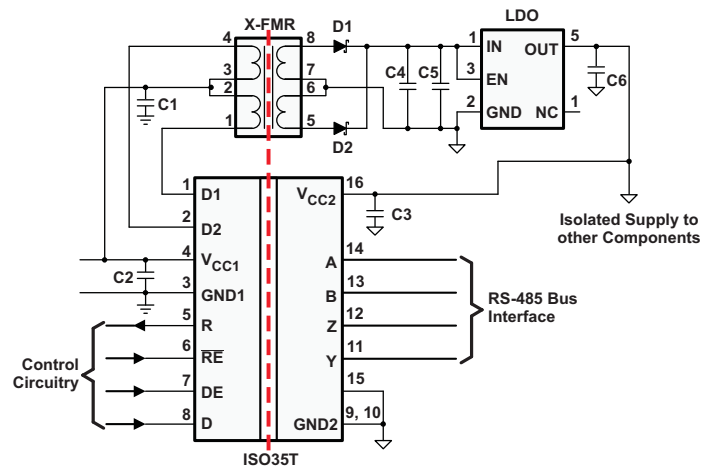
The ISO35T is specified for use from –40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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Typical Application Circuit (For details see [sluu470](#))

PIN DESCRIPTIONS

NAME	PIN #	FUNCTION
D1	1	Transformer Driver Terminal 1, Open Drain Output
D2	2	Transformer Driver Terminal 2, Open Drain Output
GND1	3	Logic-side Ground
V _{CC1}	4	Logic-side Power Supply
R	5	Receiver Output
\overline{RE}	6	Receiver Enable Input. This pin has complementary logic.
DE	7	Driver Enable Input
D	8	Driver Input
GND2	9, 15	Bus-side Ground. Both pins are internally connected.
NC	10	No Connect. This pin is not connected to any internal circuitry.
Y	11	Non-inverting Driver Output
Z	12	Inverting Driver Output
B	13	Inverting Receiver Input
A	14	Non-inverting Receiver Input
V _{CC2}	16	Bus-side Power Supply

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

				VALUE	UNIT	
V_{CC1}, V_{CC2}	Input supply voltage ⁽²⁾			−0.3 to 6	V	
V_A, V_B, V_Y, V_Z	Voltage at any bus I/O terminal (A, B, Y, Z)			−9 to 14	V	
V_{D1}, V_{D2}	Voltage at D1, D2			14	V	
$V_{(TRANS)}$	Voltage input, transient pulse through 100Ω, see Figure 12 (A,B,Y,Z)			−50 to +50	V	
V_I	Voltage input at any D, DE or \overline{RE} terminal			−0.5 to 7	V	
I_O	Receiver output current			±10	mA	
I_{D1}, I_{D2}	Transformer Driver Output Current			450	mA	
ESD	Electrostatic discharge	Human Body Model	JEDEC Standard 22, Test Method A114-C.01	Bus pins and GND1	±6	kV
				Bus pins and GND2	±16	kV
				All pins	±4	kV
		Charged Device Model	JEDEC Standard 22, Test Method C101	All pins	±1.5	kV
		Machine Model			ANSI/ESDS5.2-1996	±200
T_J	Maximum junction temperature			170	°C	
T_{STG}	Storage temperature			-65 to 150	°C	

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values except differential I/O bus voltages are with respect to network ground terminal and are peak voltage values.

RECOMMENDED OPERATING CONDITIONS

				MIN	TYP	MAX	UNIT
V_{CC1}, V_{CC2}	Supply Voltage			3.0	3.3	3.6	V
V_I or V_{IC}	Voltage at any bus terminal (separately or common-mode)			–7		12	V
V_{IH}	High-level input voltage			2		V_{CC}	V
V_{IL}	Low-level input voltage			0		0.8	V
V_{ID}	Differential input voltage			–12		12	V
R_L	Differential load resistance			54	60		Ω
I_O	Output Current			–60		60	mA
				–8		8	
T_A	Ambient temperature			–40		85	°C
T_J	Operating junction temperature			–40		150	°C
$1 / t_{UI}$	Signaling Rate					1	Mbps

SUPPLY CURRENT & COMMON MODE TRANSIENT IMMUNITY

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{CC1}^{(1)}$ Logic-side quiescent supply current	DE & \overline{RE} = 0V or V_{CC1} (Driver and Receiver Enabled or Disabled), D = 0 V or V_{CC1} , No load		4.5	8	mA
$I_{CC2}^{(1)}$ Bus-side quiescent supply current	\overline{RE} = 0 V or V_{CC1} , DE = 0 V (driver disabled), No load		7.5	13	mA
	\overline{RE} = 0 V or V_{CC1} , DE = V_{CC1} (driver enabled), D = 0 V or V_{CC1} , No Load		9	16	
CMTI Common-mode transient immunity	See Figure 13	25	50		kV/μs

- (1) I_{CC1} and I_{CC2} are measured when device is connected to external power supplies, V_{CC1} & V_{CC2} . In this case, D1 & D2 are open and disconnected from external transformer.

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RS-485 DRIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V _{OD}	Differential output voltage magnitude	I _O = 0 mA (No Load)		2.5	V _{CC2}		V
		R _L = 54 Ω (RS-485), See Figure 1		1.5	2		
		R _L = 100 Ω (RS-422) ⁽¹⁾ , See Figure 1		2	2.3		
		V _{test} = −7 V to +12 V, See Figure 2		1.5			
Δ V _{OD}	Change in magnitude of the differential output voltage	See Figure 1 and Figure 2		−0.2	0	0.2	V
V _{OC(SS)}	Steady-state common-mode output voltage	Figure 3		1	2.6	3	V
ΔV _{OC(SS)}	Change in steady-state common-mode output voltage			−0.1		0.1	V
V _{OC(pp)}	Peak-to-peak common-mode output voltage	See Figure 3		0.25			V
I _I	Input current, D & DE	V _I at 0 V or V _{CC1}		−10		10	μA
I _{OZ}	High-impedance state output current	V _Y or V _Z = 12V, V _{CC} = 0 V or 3 V, DE = 0 V	Other input at 0 V	90			μA
		V _Y or V _Z = −7 V, V _{CC} = 0 V or 3 V, DE = 0 V		−10			
I _{OS(P)} ⁽²⁾	Peak short-circuit output current	V _Y or V _Z = −7 V to +12 V, See Figure 4	Other input at 0 V	300			mA
I _{OS(SS)} ⁽²⁾	Steady-state short-circuit output current			−250			250
C _(OD)	Differential output capacitance	V _I = 0.4 sin (4E6πt) + 0.5V, DE at 0 V		16			pF

(1) $V_{CC2} = 3.3$ V \pm 5%

(2) This device has thermal shutdown and output current-limiting features to protect in short-circuit fault condition.

RS-485 DRIVER SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}, t_{PHL} Propagation delay	See Figure 5		205	340	ns
$t_{sk(p)}$ Pulse skew ($ t_{PHL} - t_{PLH} $)			1.5		
t_r Differential output signal rise time		120	185	300	
t_f Differential output signal fall time		120	180	300	
t_{PHZ} Propagation delay, high-level-to-high-impedance output	See Figure 6			205	ns
t_{PZH} Propagation delay, high-impedance-to-high-level output				530	
t_{PLZ} Propagation delay, low-level to high-impedance output	See Figure 7			330	
t_{PZL} Propagation delay, high-impedance-to-low-level output				530	

RS-485 RECEIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{IT(+)}$ Positive-going input threshold voltage	$I_O = -8$ mA			-20	mV
$V_{IT(-)}$ Negative-going input threshold voltage	$I_O = 8$ mA	-200			
V_{hys} Hysteresis voltage ($V_{IT+} - V_{IT-}$)			50		mV
V_{OH} High-level output voltage	See Figure 8	2.4		0.4	V
V_{OL} Low-level output voltage					
$I_{O(Z)}$ High-impedance state output current	$V_O = 0$ or V_{CC1} , $\overline{RE} = V_{CC1}$	-1		1	μ A

RS-485 RECEIVER ELECTRICAL CHARACTERISTICS (continued)

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_A, I_B	Bus input current	V_A or $V_B = 12\text{ V}$		50	100	μA
		V_A or $V_B = 12\text{ V}$, $V_{CC2} = 0\text{ V}$		60	100	
		V_A or $V_B = -7\text{ V}$	-100	-40		
		V_A or $V_B = -7\text{ V}$, $V_{CC2} = 0\text{ V}$	-100	-30		
I_{IH}	High-level input current, \overline{RE}	$V_{IH} = 2\text{ V}$	-10		10	μA
I_{IL}	Low-level input current, \overline{RE}	$V_{IL} = 0.8\text{ V}$	-10		10	μA
R_{ID}	Differential input resistance	Measured between A & B	96			$\text{k}\Omega$
C_{ID}	Differential input capacitance	$V_I = 0.4 \sin(4E6\pi t) + 0.5\text{ V}$, DE at 0 V		2		pF

RS-485 RECEIVER SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}, t_{PHL}	Propagation delay	See Figure 9		85	115	ns
$t_{sk(p)}$	Pulse skew ($ t_{PHL} - t_{PLH} $)				13	
t_r	Output signal rise time			1	4	
t_f	Output signal fall time			1	4	
t_{PHZ}, t_{PZH}	Propagation delay, high-level to high-impedance output Propagation delay, high-impedance to high-level output	See Figure 10 , DE at 0 V		13	25	ns
t_{PLZ}, t_{PZL}	Propagation delay, low-level to high-impedance output Propagation delay, high-impedance to low-level output	See Figure 11 , DE at 0 V		13	25	

TRANSFORMER DRIVER CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{OSC}	Oscillator frequency	$V_{CC1} = 3.3\text{ V} \pm 10\%$, D1 and D2 connected to Transformer	300	400	550	kHz
R_{ON}	Switch on resistance	D1 and D2 connected to 50 Ω pull-up resistors		1	2.5	Ω
$t_{r,D}$	D1, D2 output rise time	$V_{CC1} = 3.3\text{ V} \pm 10\%$, see Figure 14 , D1 and D2 connected to 50- Ω pull-up resistors.		70		ns
$t_{f,D}$	D1, D2 output fall time	$V_{CC1} = 3.3\text{ V} \pm 10\%$, see Figure 14 , D1 and D2 connected to 50- Ω pull-up resistors.		80		ns
f_{St}	Startup frequency	$V_{CC1} = 2.4\text{ V}$, D1 and D2 connected to Transformer		350		kHz
t_{BBM}	Break before make time delay	$V_{CC1} = 3.3\text{ V} \pm 10\%$, see Figure 14 , D1 & D2 connected to 50- Ω pull-up resistors.		140		ns

PARAMETER MEASUREMENT INFORMATION

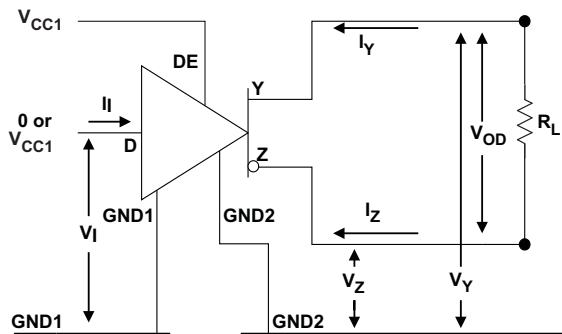
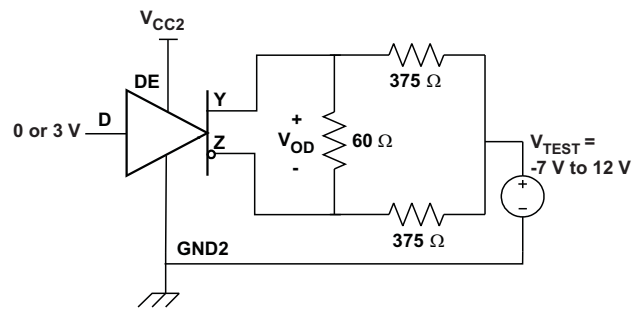
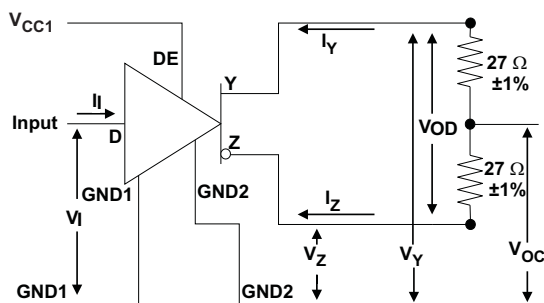

 Figure 1. Driver V_{OD} Test and Current Definitions

 Figure 2. Driver V_{OD} With Common-Mode Loading Test Circuit


Figure 3. Test Circuit and Waveform Definitions For The Driver Common-Mode Output Voltage

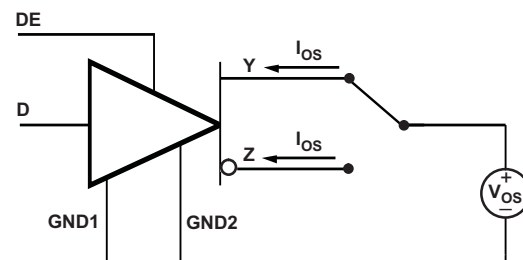
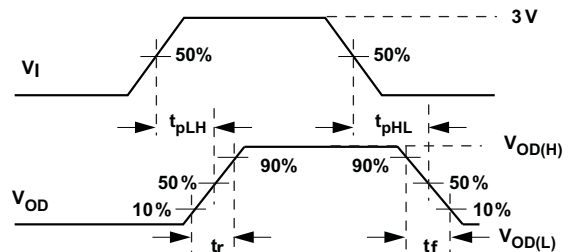
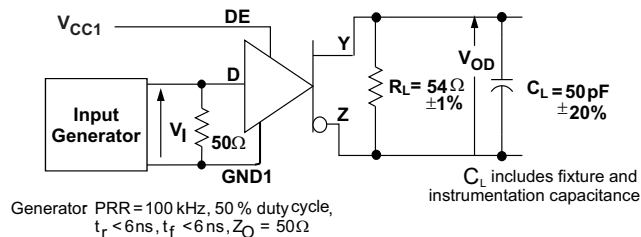

 Figure 4. Driver Short-Circuit Test Circuit and Waveforms (Short Circuit applied at Time $t=0$)


Figure 5. Driver Switching Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION (continued)

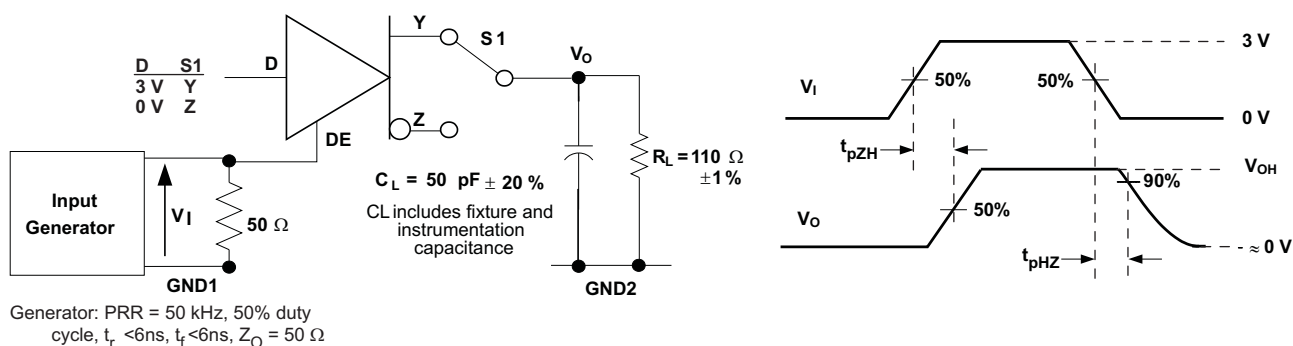


Figure 6. Driver High-Level Output Enable and Disable Time Test Circuit and Voltage Waveforms

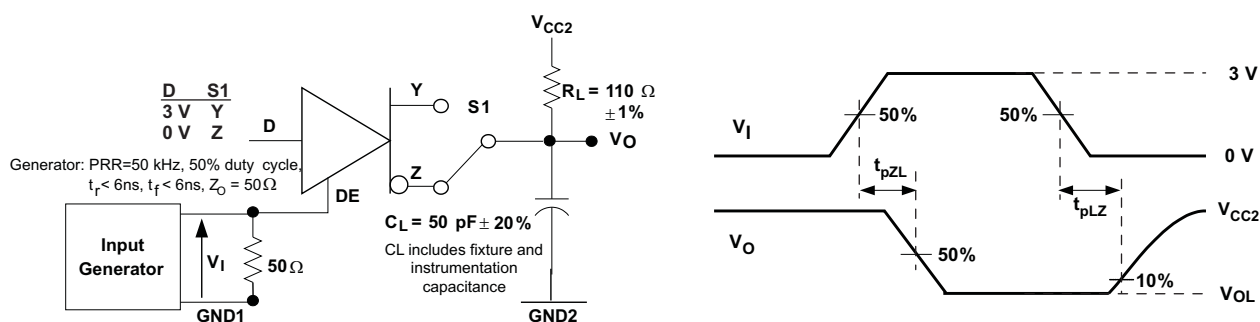


Figure 7. Driver Low-Level Output Enable and Disable Time Test Circuit and Voltage Waveform

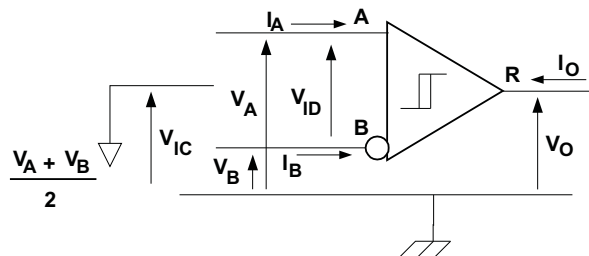


Figure 8. Receiver Voltage and Current Definitions

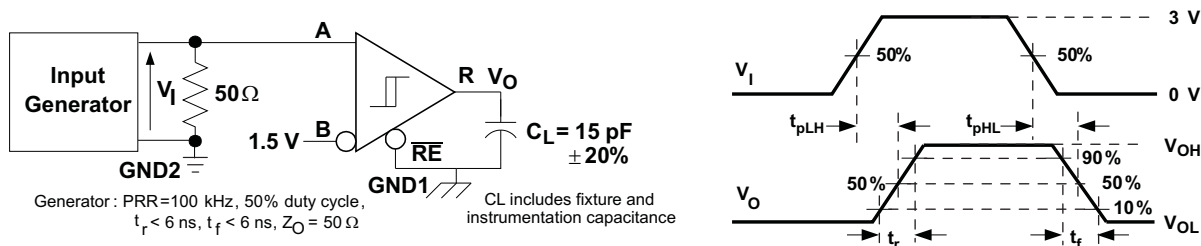
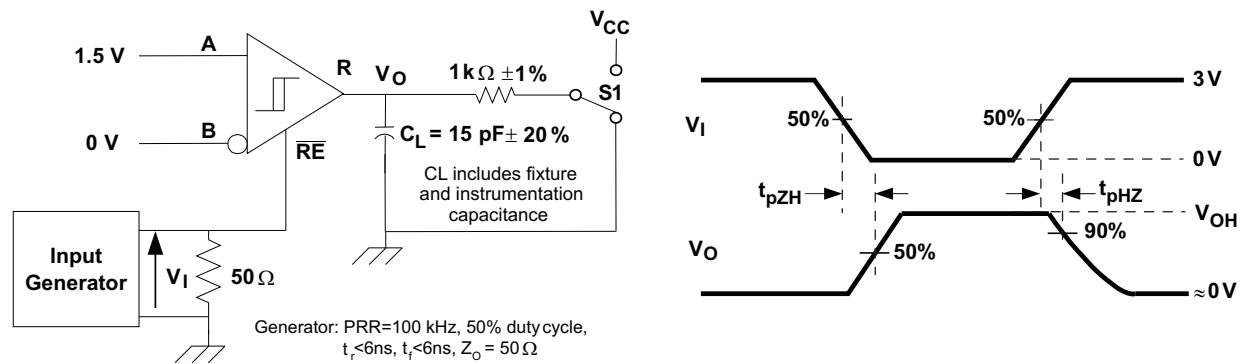
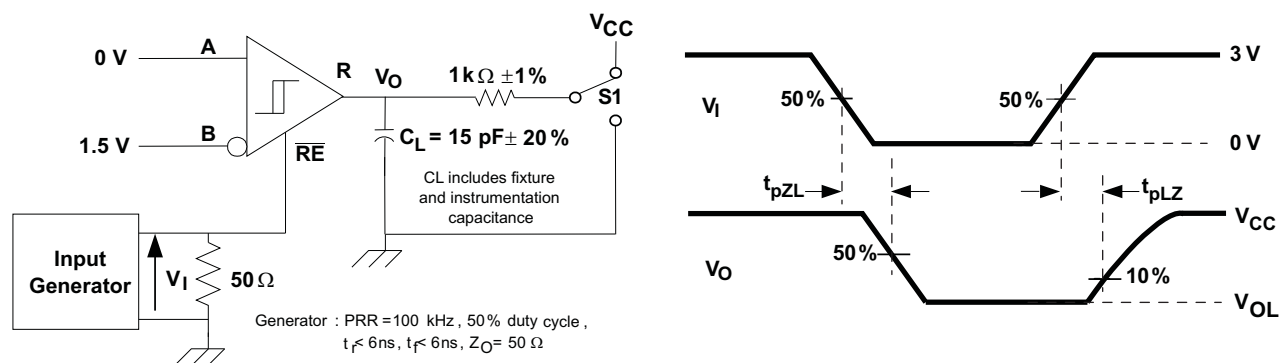
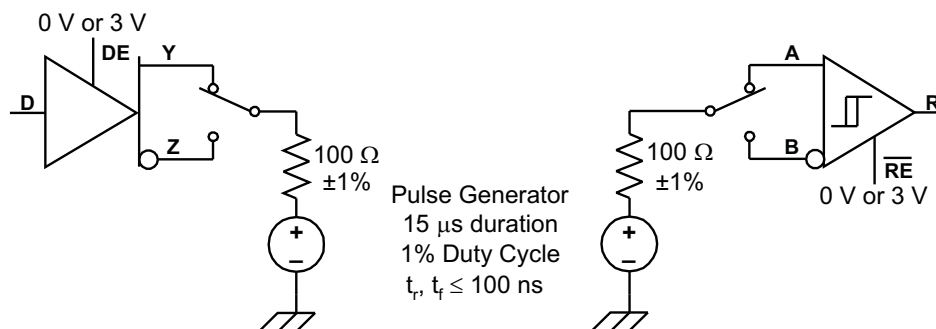


Figure 9. Receiver Switching Test Circuit and Waveforms

PARAMETER MEASUREMENT INFORMATION (continued)

Figure 10. Receiver Enable Test Circuit and Waveforms, Data Output High

Figure 11. Receiver Enable Test Circuit and Waveforms, Data Output Low

Figure 12. Transient Over-Voltage Test Circuit

PARAMETER MEASUREMENT INFORMATION (continued)

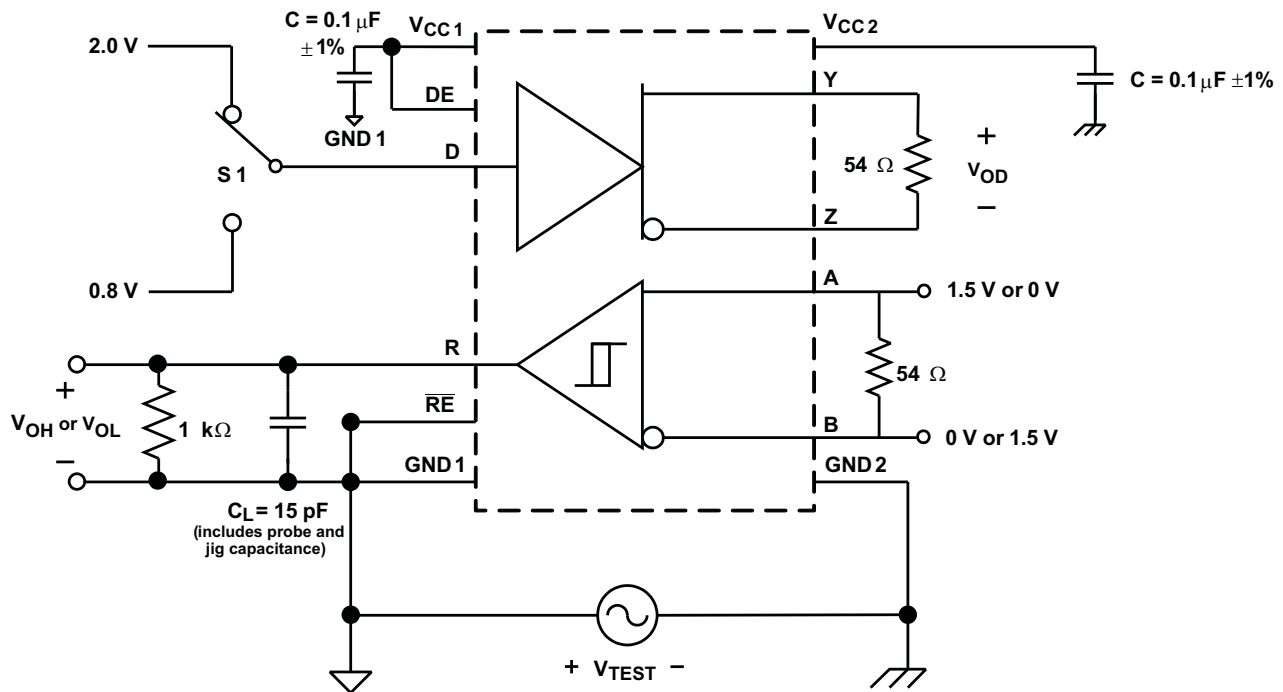


Figure 13. Common-Mode Transient Immunity Test Circuit

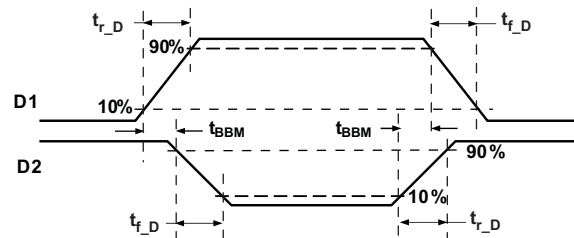


Figure 14. Transition Times and Break-Before-Make Time Delay for D1, D2 Outputs

DEVICE INFORMATION

Table 1. Driver Function Table⁽¹⁾

INPUT	ENABLE	OUTPUTS	
(D)	(DE)	Y	Z
H	H	H	L
L	H	L	H
X	L	hi-Z	hi-Z
X	OPEN	hi-Z	hi-Z
OPEN	H	H	L

(1) H = High Level, L = Low Level, X = Don't Care, hi-Z = High Impedance (Off)

Table 2. Receiver Function Table⁽¹⁾

DIFFERENTIAL INPUT $V_{ID} = (V_A - V_B)$	ENABLE (\overline{RE})	OUTPUT (R)
$-0.02\text{ V} \leq V_{ID}$	L	H
$-0.2\text{ V} < V_{ID} < -0.02\text{ V}$	L	?
$V_{ID} \leq -0.2\text{ V}$	L	L
X	H	hi-Z
X	OPEN	hi-Z
Open circuit	L	H
Short Circuit	L	H
Idle (terminated) bus	L	H

(1) H = High Level, L = Low Level, X = Don't Care, hi-Z = High Impedance (Off), ? = Indeterminate

IEC INSULATION AND SAFETY RELATED SPECIFICATIONS FOR 16-DW PACKAGE

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
L(I01) Minimum air gap (Clearance ⁽¹⁾)	Shortest terminal to terminal distance through air	8.3			mm
L(I02) Minimum external tracking (Creepage ⁽¹⁾)	Shortest terminal to terminal distance across the package surface	8.1			mm
CTI Tracking resistance(Comparative Tracking Index)	DIN IEC 60112 / VDE 0303 Part 1	400			V
Minimum Internal Gap (Internal Clearance)	Distance through the insulation	0.008			mm
R _{IO} Isolation resistance	Input to output, V _{IO} = 500 V, all pins on each side of the barrier tied together creating a two-terminal device	>10 ¹²			Ω
C _{IO} Barrier capacitance Input to output	V _{IO} = 0.4 sin (2πft), f = 1 MHz		2		pF
C _I Input capacitance to ground	V _I = V _{CC} /2 + 0.4 sin (2πft), f = 1 MHz, V _{CC} = 5 V		2		pF

- (1) Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed circuit board do not reduce this distance.

Creepage and clearance on a printed circuit board become equal according to the measurement techniques shown in the Isolation Glossary. Techniques such as inserting grooves and/or ribs on a printed circuit board are used to help increase these specifications

IEC 60664-1 RATINGS TABLE

PARAMETER	TEST CONDITIONS	SPECIFICATION
Basic isolation group	Material group	II
Installation classification	Rated mains voltage ≤ 150 V _{RMS}	I-IV
	Rated mains voltage ≤ 300 V _{RMS}	I-III
	Rated mains voltage ≤ 400 V _{RMS}	I-II

IEC 60747-5-2 INSULATION CHARACTERISTICS⁽¹⁾

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	SPECIFICATION	UNIT
V _{IORM} Maximum working insulation voltage		566	V _{peak}
V _{PR} Input to output test voltage	Method b1, V _{PR} = V _{IORM} × 1.875, 100% Production test with t = 1 s, Partial discharge < 5 pC	1062	V _{peak}
	Method a, After environmental tests subgroup 1, V _{PR} = V _{IORM} × 1.6, t = 10 s, Partial discharge < 5 pC	906	
	After Input/Output Safety Test Subgroup 2/3, V _{PR} = V _{IORM} × 1.2, t = 10 s, Partial discharge < 5 pC	680	
V _{IOTM} Transient overvoltage	t = 60 s (Qualification) t = 1 s (100% Production)	4242	V _{peak}
V _{IOSM} Maximum surge voltage	Tested per IEC 60065 (Qualification Test)	4242	V _{peak}
R _S Insulation resistance	V _{IO} = 500 V at T _S	> 10 ⁹	Ω
Pollution degree		2	

- (1) Climatic Classification 40/125/21

REGULATORY INFORMATION

VDE	UL
Certified according to DIN EN 60747-5-2 (VDE 0884 Part 2)	Recognized under 1577 Component Recognition Program
Basic Insulation Maximum Transient Overvoltage, 4242 V _{PK} Maximum Surge Voltage, 4242 V _{PK} Maximum Working Voltage, 566 V _{PK}	Single / Basic Isolation Voltage, 2500 V _{RMS} ⁽¹⁾
File Number: 40016131 (Approval Pending)	File Number: E181974 (Approval Pending)

(1) Production tested ≥ 3000 V_{RMS} for 1 second in accordance with UL 1577.

IEC SAFETY LIMITING VALUES

Safety limiting intends to prevent potential damage to the isolation barrier upon failure of input or output circuitry. A failure of the IO can allow low resistance to ground or the supply. Without current limiting, sufficient power is dissipated to overheat the die; and, damage the isolation barrier—potentially leading to secondary system failures.

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
I _S Safety input, output, or supply current	DW-16	$\theta_{JA} = 80.5^{\circ}\text{C/W}$, V _I = 3.6V, T _J = 170°C, T _A = 25°C			500	mA
T _S Maximum case temperature					150	°C

The safety-limiting constraint is the absolute maximum junction temperature specified in the absolute maximum ratings table. The power dissipation and junction-to-air thermal impedance of the device installed in the application hardware determines the junction temperature. The assumed junction-to-air thermal resistance in the Thermal Characteristics table is that of a device installed on the High-K Test Board for Leaded Surface Mount Packages. The power is the recommended maximum input voltage times the current. The junction temperature is then the ambient temperature plus the power times the junction-to-air thermal resistance.

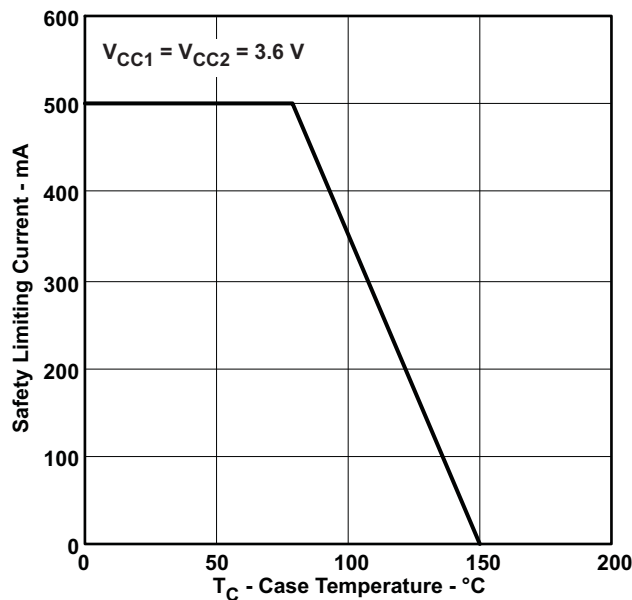


Figure 15. DW-16 θ_{JC} Thermal Derating Curve per IEC 60747-5-2

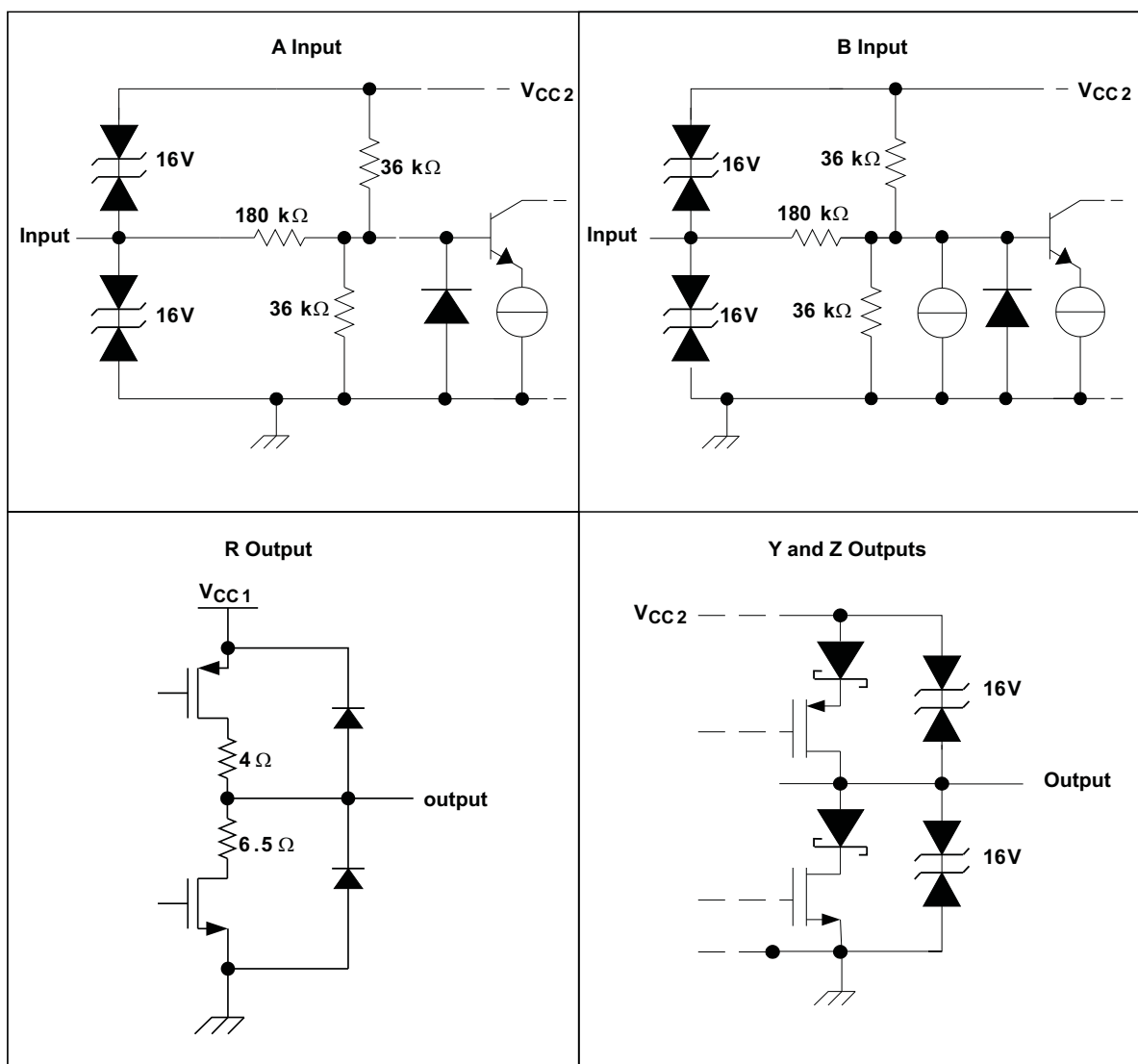
THERMAL INFORMATION

THERMAL METRIC ⁽¹⁾		ISO35T	UNITS
		DW	
		16 PINS	
θ_{JA}	Junction-to-ambient thermal resistance	80.5	°C/W
$\theta_{JC(TOP)}$	Junction-to-case(top) thermal resistance	43.8	
θ_{JB}	Junction-to-board thermal resistance	49.7	
ψ_{JT}	Junction-to-top characterization parameter	13.8	
ψ_{JB}	Junction-to-board characterization parameter	41.4	
$\theta_{JC(BOTTOM)}$	Junction-to-case(bottom) thermal resistance	n/a	
$P_D^{(2)}$	$V_{CC1} = V_{CC2} = 3.6V$, $T_J = 150^\circ C$, $R_L = 54\Omega$, $C_L = 50pF$ (Driver), $C_L = 15pF$ (Receiver), Input a 0.5 MHz 50% duty cycle square wave to Driver and Receiver	373	mW

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

(2) P_D = Maximum device power dissipation

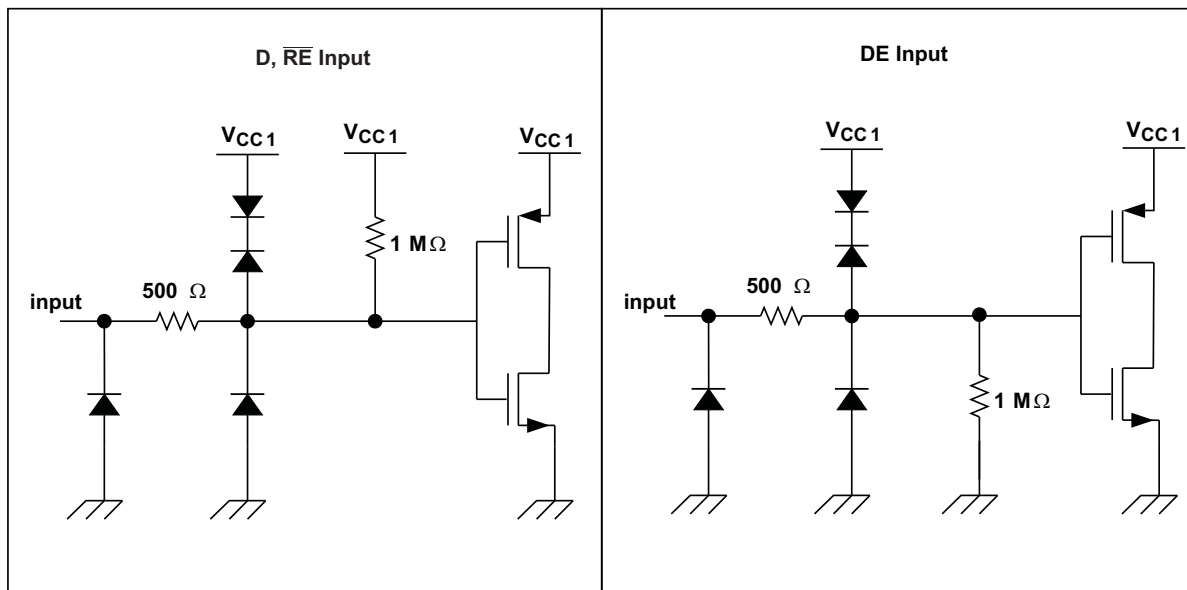
EQUIVALENT CIRCUIT SCHEMATICS



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TYPICAL CHARACTERISTICS

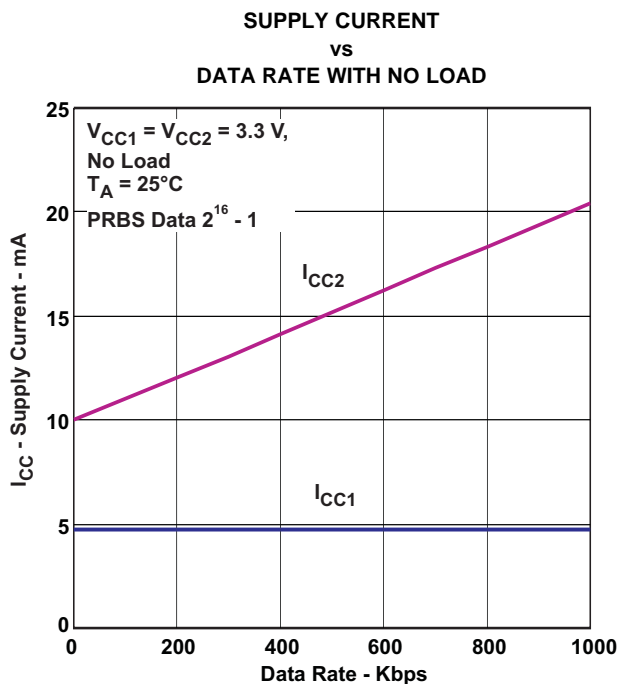


Figure 16.

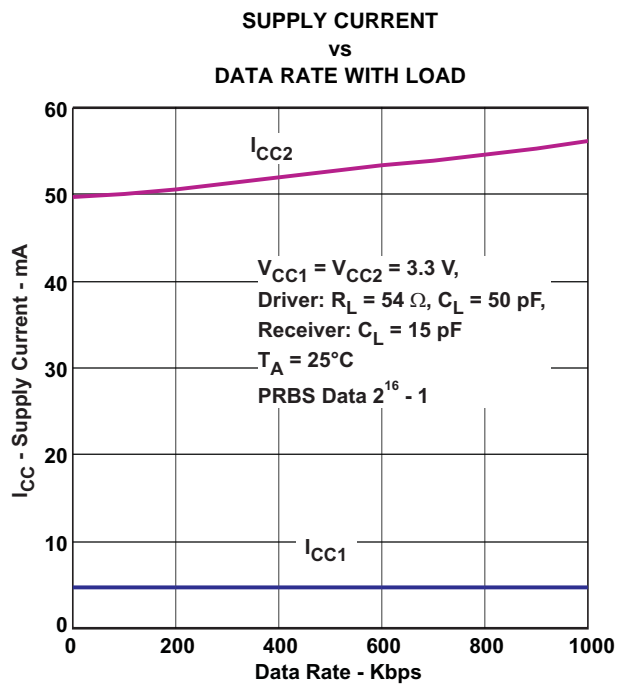


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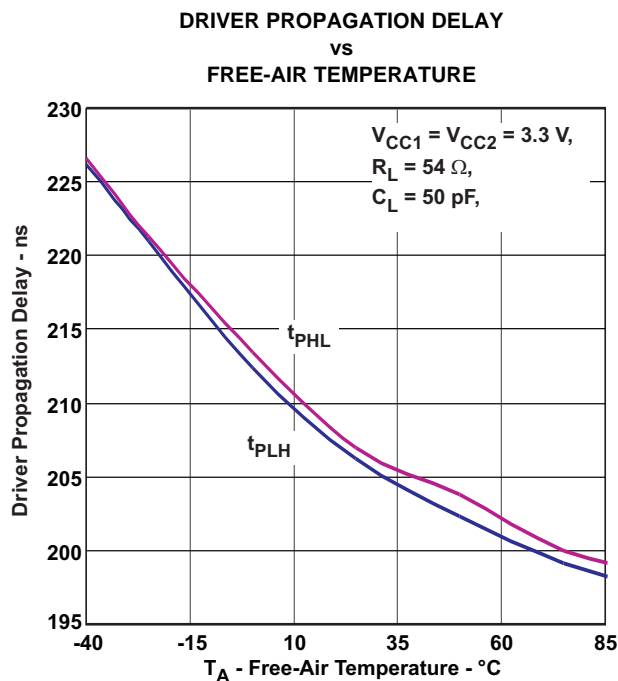


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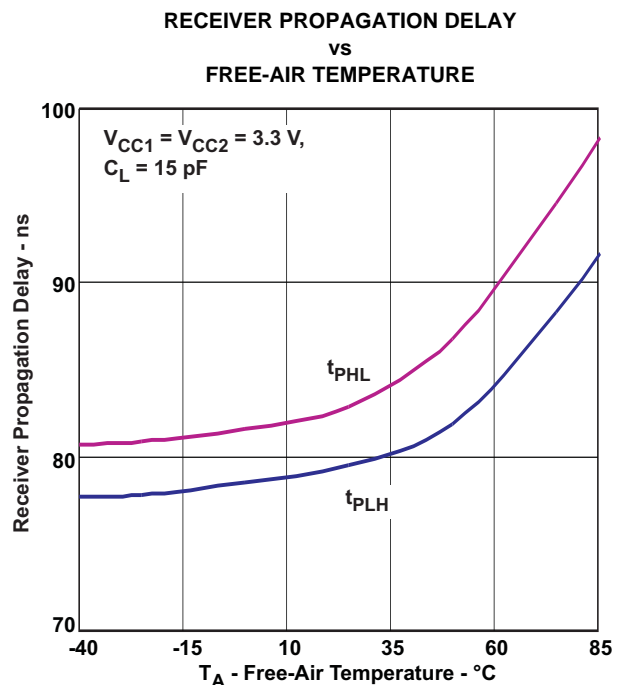


Figure 19.

TYPICAL CHARACTERISTICS (continued)

DRIVER RISE, FALL TIME
vs
FREE-AIR TEMPERATURE

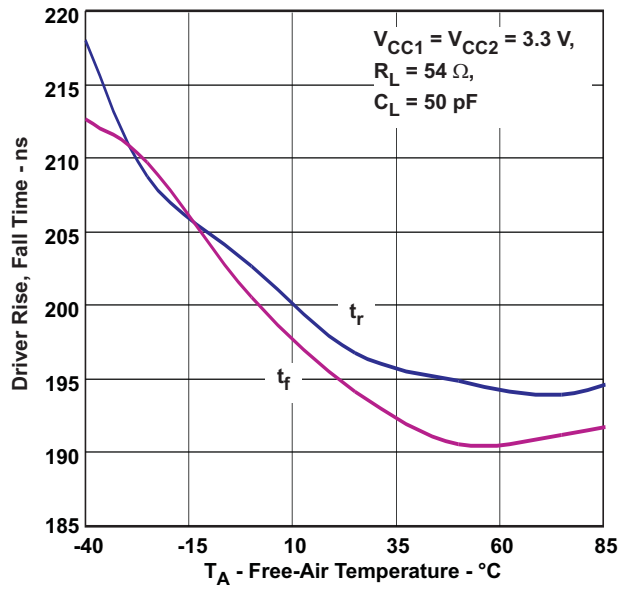


Figure 20.

RECEIVER RISE, FALL TIME
vs
FREE-AIR TEMPERATURE

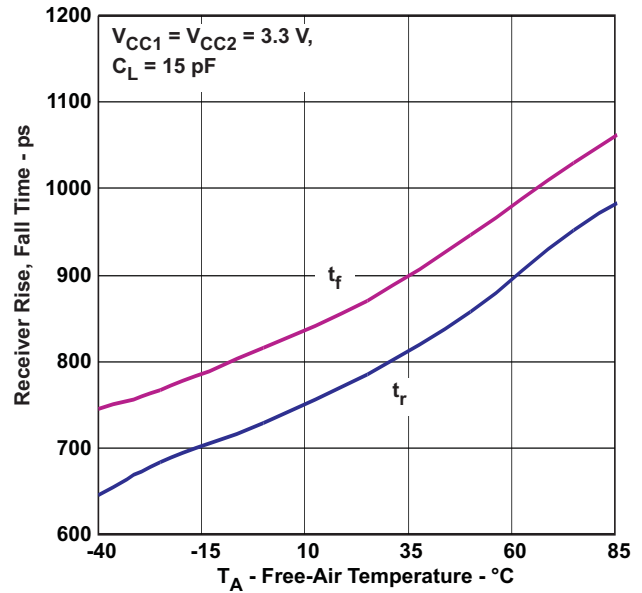


Figure 21.

DIFFERENTIAL OUTPUT VOLTAGE
vs
LOAD CURRENT

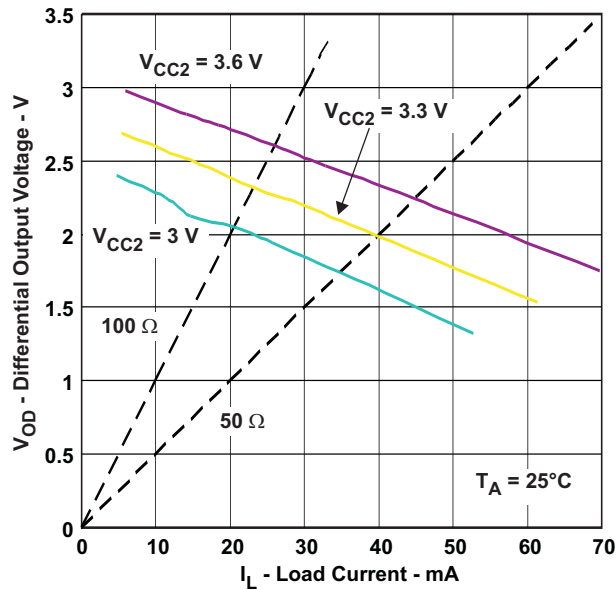


Figure 22.

RECEIVER LOW-LEVEL OUTPUT CURRENT
vs
LOW-LEVEL OUTPUT VOLTAGE

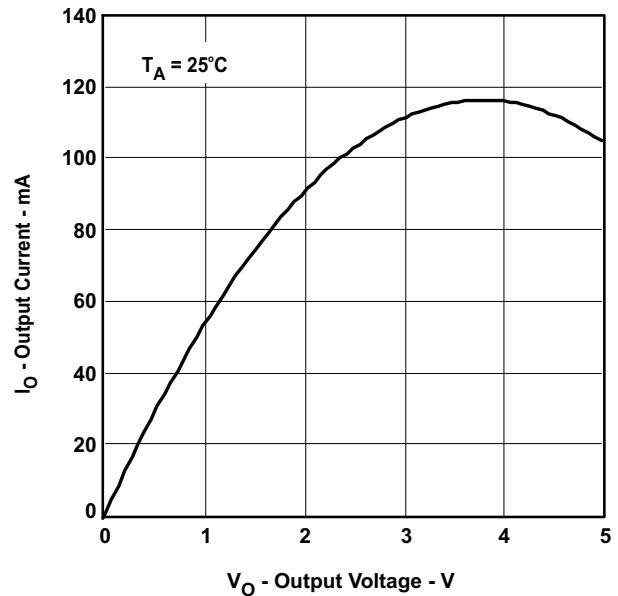


Figure 23.

TYPICAL CHARACTERISTICS (continued)

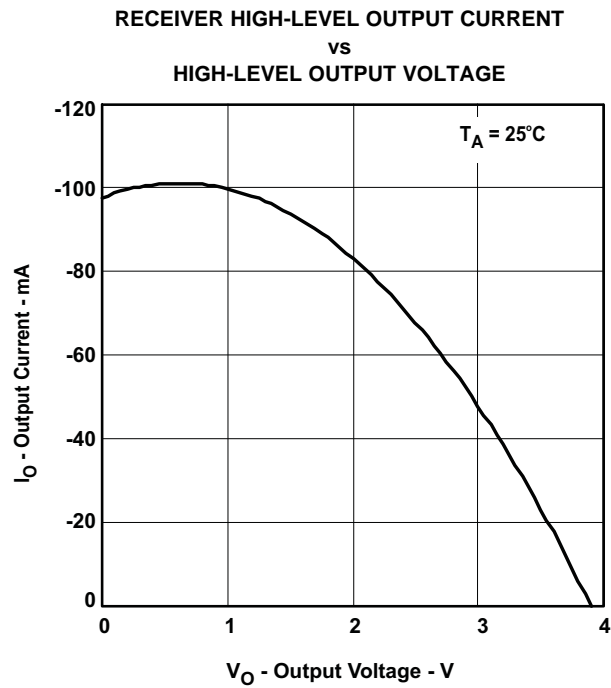


Figure 24.

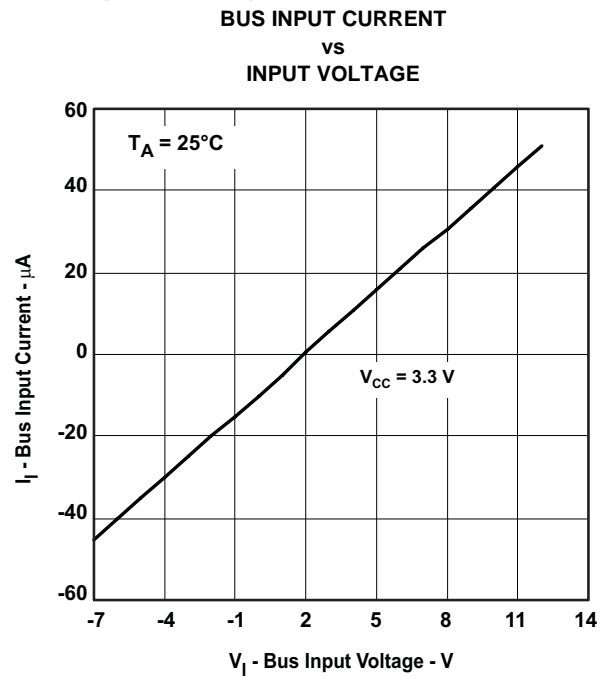


Figure 25.

APPLICATION INFORMATION

REFERENCE DESIGN

ISO35T Reference design ([sluu470](#)) and miniature evaluation boards are available to provide a complete isolated data and power solution.

TRANSIENT VOLTAGES

Isolation of a circuit insulates it from other circuits and earth so that noise develops across the insulation rather than circuit components. The most common noise threat to data-line circuits is voltage surges or electrical fast transients that occur after installation and the transient ratings of ISO35T are sufficient for all but the most severe installations. However, some equipment manufacturers use their ESD generators to test transient susceptibility of their equipment and can easily exceed insulation ratings. ESD generators simulate static discharges that may occur during device or equipment handling with low-energy but very high voltage transients.

Figure 26 models the ISO35T bus IO connected to a noise generator. C_{IN} and R_{IN} is the device and any other stray or added capacitance or resistance across the A or B pin to GND2, C_{ISO} and R_{ISO} is the capacitance and resistance between GND1 and GND2 of ISO35T plus those of any other insulation (transformer, etc.), and we assume stray inductance negligible. From this model, the voltage at the isolated bus return is

$$V_{GND2} = V_N \frac{Z_{ISO}}{Z_{ISO} + Z_{IN}} \text{ and will always be less than 16 V from } V_N.$$

If ISO35T is tested as a stand-alone device, $R_{IN} = 6 \times 10^4 \Omega$, $C_{IN} = 16 \times 10^{-12} \text{ F}$, $R_{ISO} = 10^9 \Omega$ and $C_{ISO} = 10^{-12} \text{ F}$.

Note from **Figure 26** that the resistor ratio determines the voltage ratio at low frequency and it is the inverse capacitance ratio at high frequency. In the stand-alone case and for low frequency,

$$\frac{V_{GND2}}{V_N} = \frac{R_{ISO}}{R_{ISO} + R_{IN}} = \frac{10^9}{10^9 + 6 \times 10^4}$$

or essentially all noise appears across the barrier.

At very high frequency,

$$\frac{V_{GND2}}{V_N} = \frac{\frac{1}{C_{ISO}}}{\frac{1}{C_{ISO}} + \frac{1}{C_{IN}}} = \frac{1}{1 + \frac{C_{ISO}}{C_{IN}}} = \frac{1}{1 + \frac{1}{16}} = 0.94$$

and 94% of V_N appears across the barrier. As long as R_{ISO} is greater than R_{IN} and C_{ISO} is less than C_{IN} , most of transient noise appears across the isolation barrier, as it should.

We recommend the reader not test equipment transient susceptibility with ESD generators or consider product claims of ESD ratings above the barrier transient ratings of an isolated interface. ESD is best managed through recessing or covering connector pins in a conductive connector shell and installer training.

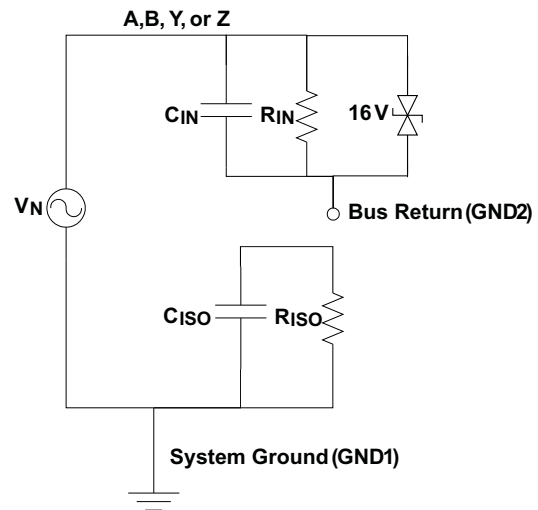


Figure 26. Noise Model

REVISION HISTORY

Changes from Original (November 2010) to Revision A Page

- Changed the data sheet From: Product Preview To: Production data 1

Changes from Revision A (March 2011) to Revision B Page

- Changed pin 16 From: V_{CC1} To: V_{CC2} in the DW Package drawing 1

Changes from Revision B (June 2011) to Revision C Page

- Deleted MIN and MAX values from the t_{r_D} , t_{f_D} , and t_{BBM} specifications in theTransformer Driver Chara table. 5
- Changed conditions statement from 1.9V to 2.4V; and changed TYP value from 230 to 350 for f_{St} specification in Transformer Driver Characteristics table. 5
- Added "D1 and D2 connected to 50-Ω pull-up resistors" to conditions statement for t_{r_D} , t_{f_D} , and t_{BBM} specifications in theTransformer Driver Chara table. 5

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
ISO35TDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ISO35TDW	Samples
ISO35TDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ISO35TDW	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ISO35TDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ISO35TDWR	SOIC	DW	16	2000	367.0	367.0	38.0

DW (R-PDSO-G16)

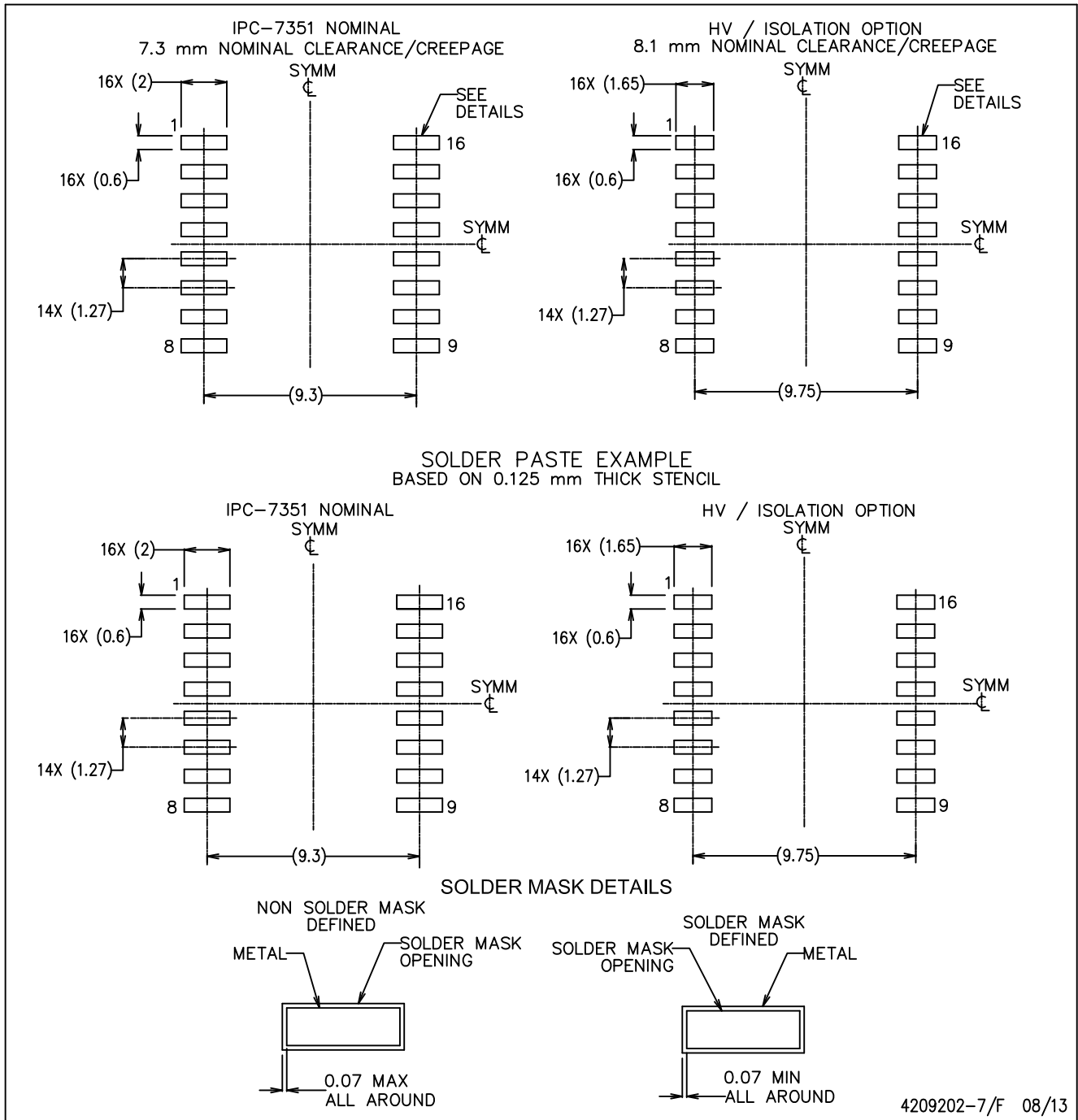
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-013 variation AA.

DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Refer to IPC7351 for alternate board design.
 - Solder mask tolerances between and around signal pads can vary based on board fabrication site.
 - Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
 - Board assembly site may have different recommendations for stencil design.

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